



Product Summary

V _{(BR)DSS}	R _{DS(on)} max	I_D max T _A = +25°C (Note 6)
2017	20mΩ @ V _{GS} = 4.5V	9.8A
20V	28mΩ @ V _{GS} = 2.5V	8.3A

Description and Applications

This MOSFET has been designed to minimize the on-state resistance (R_{DS(on)}) and yet maintain superior switching performance, making it ideal for high efficiency power management applications.

- Battery charging
- Power management functions
- **DC-DC** converters
- Portable power adaptors

20V N-CHANNEL ENHANCEMENT MODE MOSFET

Features and Benefits

- Low On-Resistance
- Low Input Capacitance
- Fast Switching Speed
- Low Output Leakage
- ESD Protected Up to 2kV
- Totally Lead-Free & Fully RoHS Compliant (Notes 1 & 2)
- Halogen and Antimony Free. "Green" Device (Note 3)
- Qualified to AEC-Q101 Standards for High Reliability

Mechanical Data

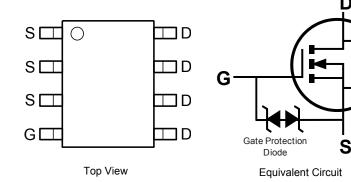
- Case: SO-8 •
- Case Material: Molded Plastic, "Green" Molding Compound. UL Flammability Classification Rating 94V-0 (Note 1)
- Moisture Sensitivity: Level 1 per J-STD-020
- Terminal Connections: See Diagram Below
- Terminals: Finish Matte Tin annealed over Copper leadframe. Solderable per MIL-STD-202, Method 208
- Weight: 0.074 grams (approximate)





SO-8

Top View



Ordering Information (Note 4)

Product	Marking	Reel size (inches)	Tape width (mm)	Quantity per reel
DMN2028USS-13	N2028US	13	12	2,500

1. No purposely added lead. Fully EU Directive 2002/95/EC (RoHS) & 2011/65/EU (RoHS 2) compliant.

2. See http://www.diodes.com/quality/lead_free.html for more information about Diodes Incorporated's definitions of Halogen- and Antimony-free, "Green"

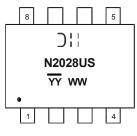
and Lead-free.

Notes:

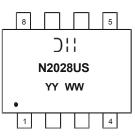
3. Halogen- and Antimony-free "Green" products are defined as those which contain <900ppm bromine, <900ppm chlorine (<1500ppm total Br + Cl) and <1000ppm antimony compounds.

4. For packaging details, go to our website at http://www.diodes.com/products/packages.html.

Marking Information



Chengdu A/T Site



Shanghai A/T Site

) | | = Manufacturer's Marking N2028US = Product Type Marking Code YYWW = Date Code Marking YY or \overline{YY} = Year (ex: 13 = 2013) WW = Week (01 - 53) YY = Date Code Marking for SAT (Shanghai Assembly/ Test site) YY = Date Code Marking for CAT (Chengdu Assembly/ Test site)



Maximum Ratings (@T_A = +25°C, unless otherwise specified.)

Characteristic			Symbol	Value	Unit
Drain-Source voltage			V _{DSS}	20	V
Gate-Source voltage		V _{GS}	±12	V	
		(Note 6)		9.8	
Continuous Drain current V _{GS}	$V_{GS} = 4.5V$	$T_A = +70^{\circ}C$ (Note 6)	I _D	7.9	
		(Note 5)		7.3	А
Pulsed Drain current	V _{GS} = 4.5V	(Note 7)	I _{DM}	45.0	
Continuous Source current (Body diode)		(Note 6)	Is	6.0	
Pulsed Source current (Body diode)		(Note 7)	I _{SM}	45.0	

Thermal Characteristics (@T_A = +25°C, unless otherwise specified.)

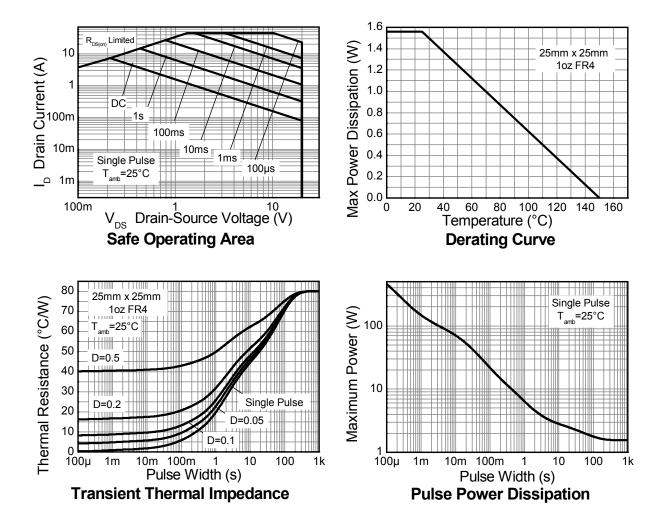
Characteristic		Symbol	Value	Unit	
Power dissipation	(Note 5)		1.56 12.5	W	
Linear derating factor	(Note 6)	PD	2.81 22.5	mW/°C	
Thermal Resistance, Junction to Ambient	(Note 5)		80.0		
	(Note 6)	R _{θJA}	44.5	°C/W	
Thermal Resistance, Junction to Lead	(Note 8)	$R_{ ext{ heta}JL}$	37.0		
Operating and storage temperature range		T _J , T _{STG}	-55 to +150	°C	

5. For a device surface mounted on 25mm x 25mm x 1.6mm FR4 PCB with high coverage of single sided 1oz copper, in still air conditions; the device is measured when operating in a steady-state condition.
6. Same as note (5), except the device is measured at t ≤ 10 sec.
7. Same as note (5), except the device is pulsed with D = 0.02 and pulse width 300µs.
9. The result work of the device is pulsed with 0 = 0.02 and pulse width 300µs. Notes:

8. Thermal resistance from junction to solder-point (at the end of the drain lead).



Thermal Characteristics



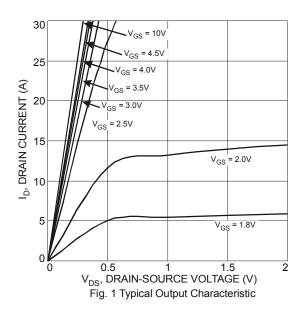


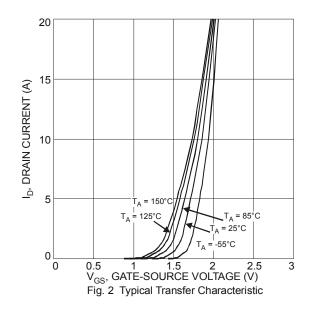
Electrical Characteristics (@T_A = +25°C, unless otherwise specified.)

Characteristic	Symbol	Min	Тур	Max	Unit	Test Condition		
OFF CHARACTERISTICS		1			•	1		
Drain-Source Breakdown Voltage	BV _{DSS}	20	-	-	V	V _{GS} = 0V, I _D = 250µA		
Zero Gate Voltage Drain Current	I _{DSS}	-	-	1.0	μA	V _{DS} = 20V, V _G	_S = 0V	
Gate-Source Leakage	I _{GSS}	-	-	±10	μA	$V_{GS} = \pm 12V, V_{DS} = 0V$		
ON CHARACTERISTICS								
Gate Threshold Voltage	V _{GS(th)}	0.6	1.0	1.3	V	$V_{DS} = V_{GS}, I_D :$	= 250µA	
Static Drain-Source On-Resistance (Note 9)	D		11	20	mΩ	V _{GS} = 4.5V, I _D = 9.4A		
Static Drain-Source On-Resistance (Note 9)	R _{DS (ON)}	-	15	28	11152	V_{GS} = 2.5V, I_D	= 8.3A	
Forward Transfer Admittance (Note 9 & 10)	Y _{fs}	-	16	-	S	V _{DS} = 5V, I _D = 9.4A		
Diode Forward Voltage (Note 9)	V _{SD}	-	0.7	1.3	V	V _{GS} = 0V, I _S = 1.3A		
DYNAMIC CHARACTERISTICS (Note 10)								
Input Capacitance	Ciss	-	1000	-				
Output Capacitance	Coss	-	166	-	pF	pF $V_{DS} = 10V, V_{GS} = 0V, f = 1.0MHz$		
Reverse Transfer Capacitance	Crss	-	158	-				
Gate Resistance	Rg	-	1.51	-	Ω	V _{DS} = 0V, V _{GS} = 0V, f = 1MHz		
Total Gate Charge (Note 11)	Qg	-	7.0	-		$\frac{V_{GS} = 2.5V}{V_{GS} = 4.5V} V_{DS} = 10V I_{D} = 9.4A$		
Total Gate Charge (Note 11)	Qg	-	11.6	-	nC		V _{DS} = 10V	
Gate-Source Charge (Note 11)	Q _{gs}	-	2.7	-	IIC		I _D = 9.4A	
Gate-Drain Charge (Note 11)	Q _{gd}	-	3.4	-				
Turn-On Delay Time (Note 11)	t _{D(on)}	-	11.67	-		V _{GS} = 4.5V, V _{DS} = 10V,		
Turn-On Rise Time (Note 11)	tr	-	12.49	-				
Turn-Off Delay Time (Note 11)	t _{D(off)}	-	35.89	-	ns	$R_G = 6\Omega$, $I_D =$	$_{\rm G} = 6\Omega$, $I_{\rm D} = 1$ A	
Turn-Off Fall Time (Note 11)	t _f	-	12.33	-	1			

Notes:

Measured under pulsed conditions. Pulse width ≤ 300µs; duty cycle ≤ 2%
 For design aid only, not subject to production testing.
 Switching characteristics are independent of operating junction temperatures.





= 150°C

T_A = 125°C

T_A = 85°C

= 25°C

Г_А = -55°С

20

15

50

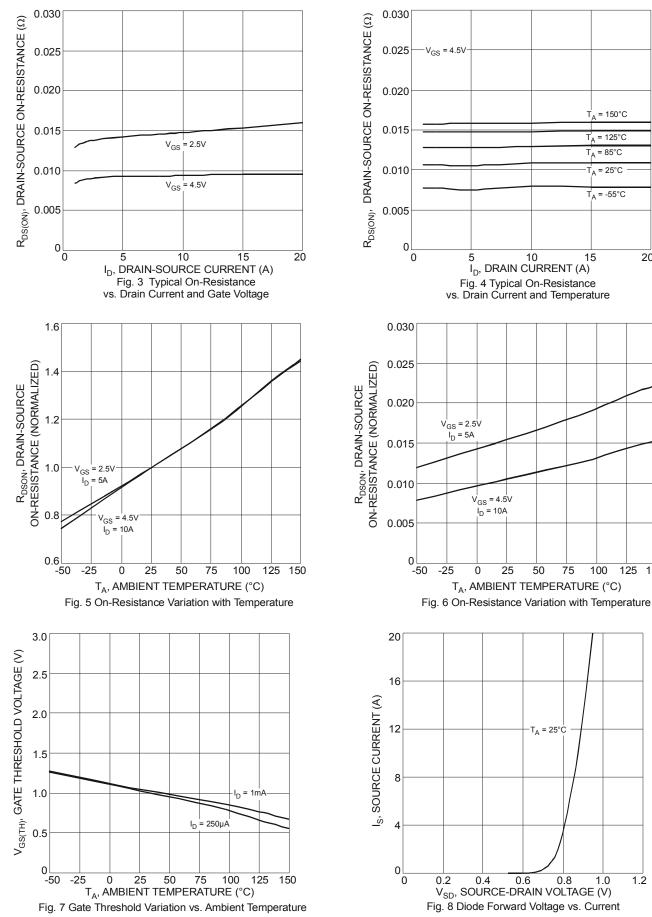
T_A = 25°Ċ

75

100

125 150

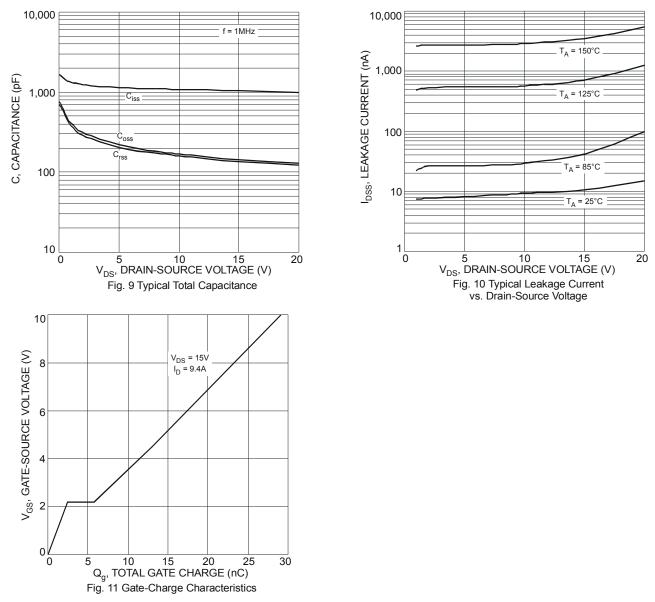




1.2

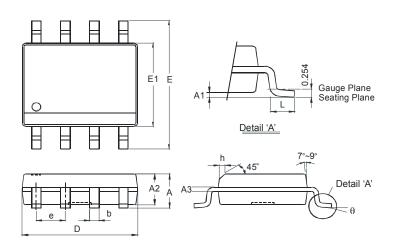
DMN2028USS





Package Outline Dimensions

Please see AP02002 at http://www.diodes.com/datasheets/ap02002.pdf for latest version.



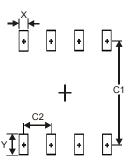
SO-8				
Dim	Min	Max		
Α	-	1.75		
A1	0.10	0.20		
A2	1.30	1.50		
A3	0.15	0.25		
b	0.3	0.5		
D	4.85	4.95		
Е	5.90	6.10		
E1	3.85	3.95		
е	1.27	Тур		
h	-	0.35		
L	0.62	0.82		
θ	0°	8°		
All Dimensions in mm				

DMN2028USS Document number: DS32075 Rev. 4 - 2



Suggested Pad Layout

Please see AP02001 at http://www.diodes.com/datasheets/ap02001.pdf for the latest version.



Dimensions	Value (in mm)
Х	0.60
Y	1.55
C1	5.4
C2	1.27

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